### INTEGRATED CIRCUITS

## DATA SHEET

# **74LVC2G126**Dual bus buffer/line driver; 3-state

Product specification Supersedes data of 2003 Mar 10 2003 Sep 01





### Dual bus buffer/line driver; 3-state

### 74LVC2G126

#### **FEATURES**

- Wide supply voltage range from 1.65 to 5.5 V
- 5 V tolerant input/output for interfacing with 5 V logic
- · High noise immunity
- Complies with JEDEC standard:
  - JESD8-7 (1.65 to 1.95 V)
  - JESD8-5 (2.3 to 2.7 V)
  - JESD8B/JESD36 (2.7 to 3.6 V).
- ESD protection:
  - HBM EIA/JESD22-A114-A exceeds 2000 V
  - MM EIA/JESD22-A115-A exceeds 200 V.
- ±24 mA output drive (V<sub>CC</sub> = 3.0 V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- · Direct interface with TTL levels
- · Inputs accept voltages up to 5 V
- SOT505-2 and SOT765-1 package
- Specified from -40 to +85 °C and -40 to +125 °C.

#### DESCRIPTION

The 74LVC2G126 is a high-performance, low-power, low-voltage, Si-gate CMOS device and superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3 or 5 V devices. These feature allows the use of these devices as translators in a mixed 3.3 and 5 V environment.

This device is fully specified for partial power-down applications using  $I_{\text{off}}$ . The  $I_{\text{off}}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

The 74LVC2G126 provides a dual non-inverting buffer/line driver with 3-state output. The 3-state output is controlled by the output enable input (pin nOE). A LOW-level at pin nOE causes the output to assume a high-impedance OFF-state. Schmitt-trigger action at all inputs makes the circuit highly tolerant for slower input rise and fall times.

#### **QUICK REFERENCE DATA**

GND = 0 V;  $T_{amb}$  = 25 °C.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay inputs nA to output nY	$V_{CC} = 1.8 \text{ V}; C_L = 30 \text{ pF}; R_L = 1 \text{ k}\Omega$	3.9	ns
		$V_{CC} = 2.5 \text{ V}; C_L = 30 \text{ pF}; R_L = 500 \Omega$	2.6	ns
		$V_{CC} = 2.7 \text{ V}; C_L = 50 \text{ pF}; R_L = 500 \Omega$	2.8	ns
		$V_{CC} = 3.3 \text{ V}; C_L = 50 \text{ pF}; R_L = 500 \Omega$	2.4	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 50 \text{ pF}; R_L = 500 \Omega$	1.9	ns
C <sub>I</sub>	input capacitance		2	pF
C <sub>PD</sub>	power dissipation capacitance per buffer	output enabled; notes 1 and 2	17	pF
		output disabled; notes 1 and 2	5	pF

#### Notes

1.  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in Volts;

N = total load switching outputs;

 $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$ 

2. The condition is  $V_1 = GND$  to  $V_{CC}$ .

### Dual bus buffer/line driver; 3-state

74LVC2G126

#### **FUNCTION TABLE**

See note 1.

INF	OUTPUT	
nOE	nA	nY
Н	L	L
Н	Н	Н
L	X	Z

#### Note

1. H = HIGH voltage level;

L = LOW voltage level;

X = don't care;

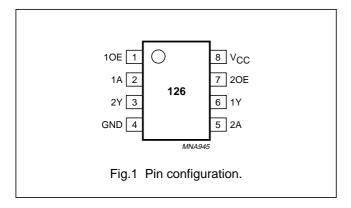
Z = high-impedance OFF-state.

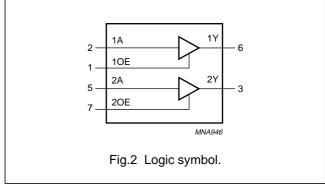
#### **ORDERING INFORMATION**

	PACKAGE							
TYPE NUMBER	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE	MARKING		
74LVC2G126DP	–40 to +125 °C	8	TSSOP8	plastic	SOT505-2	V126		
74LVC2G126DC	-40 to +125 °C	8	VSSOP8	plastic	SOT765-1	V26		

### **PINNING**

PIN	SYMBOL	DESCRIPTION
1	10E	output enable input
2	1A	data input
3	2Y	data output
4	GND	ground (0 V)
5	2A	data input
6	1Y	data output
7	20E	output enable input
8	V <sub>CC</sub>	supply voltage





### Dual bus buffer/line driver; 3-state

74LVC2G126

#### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CC</sub>	supply voltage		1.65	5.5	V
VI	input voltage		0	5.5	V
Vo	output voltage	V <sub>CC</sub> = 1.65 to 5.5 V; enable mode	0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 1.65 to 5.5 V; disable mode	0	5.5	V
		V <sub>CC</sub> = 0 V; Power-down mode	0	5.5	V
T <sub>amb</sub>	operating ambient temperature		-40	+125	°C
t <sub>r</sub> , t <sub>f</sub>	input rise and fall times	V <sub>CC</sub> = 1.65 to 2.7 V	0	20	ns/V
		V <sub>CC</sub> = 2.7 to 5.5 V	0	10	ns/V

#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CC</sub>	supply voltage		-0.5	+6.5	V
I <sub>IK</sub>	input diode current	V <sub>I</sub> < 0	_	-50	mA
VI	input voltage	note 1	-0.5	+6.5	V
I <sub>OK</sub>	output diode current	V <sub>O</sub> > V <sub>CC</sub> or V <sub>O</sub> < 0	_	±50	mA
Vo	output voltage	enable mode; notes 1 and 2	-0.5	V <sub>CC</sub> + 0.5	V
		disable mode; notes 1 and 2	-0.5	+6.5	V
		Power-down mode; notes 1 and 2	-0.5	+6.5	V
I <sub>O</sub>	output source or sink current	$V_{O} = 0$ to $V_{CC}$	_	±50	mA
I <sub>CC</sub> , I <sub>GND</sub>	V <sub>CC</sub> or GND current		_	±100	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>D</sub>	power dissipation	$T_{amb} = -40 \text{ to } +125 ^{\circ}\text{C}$	_	300	mW

#### Notes

- 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- 2. When  $V_{CC} = 0 \text{ V}$  (Power-down mode), the output voltage can be 5.5 V in normal operation.

### Dual bus buffer/line driver; 3-state

74LVC2G126

### **DC CHARACTERISTICS**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	DADAMETED	TEST COND	ITIONS	NAIN!	TVD	TVD	
	PARAMETER	OTHER	V <sub>CC</sub> (V)	MIN.	TYP.	MAX.	UNIT
T <sub>amb</sub> = -40	) to +85 °C; note 1		•	•	1		
V <sub>IH</sub>	HIGH-level input voltage		1.65 to 1.95	$0.65 \times V_{CC}$	_	_	V
			2.3 to 2.7	1.7	_	_	V
			2.7 to 3.6	2.0	_	_	٧
			4.5 to 5.5	$0.7 \times V_{CC}$	_	_	V
V <sub>IL</sub>	LOW-level input voltage		1.65 to 1.95	_	_	$0.35 \times V_{CC}$	V
			2.3 to 2.7	_	_	0.7	V
			2.7 to 3.6	_	_	0.8	V
			4.5 to 5.5	_	_	$0.3 \times V_{CC}$	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$					
		I <sub>O</sub> = 100 μA	1.65 to 5.5	_	_	0.1	V
		$I_O = 4 \text{ mA}$	1.65	_	_	0.45	V
		$I_O = 8 \text{ mA}$	2.3	_	_	0.3	V
		I <sub>O</sub> = 12 mA	2.7	_	_	0.4	V
		I <sub>O</sub> = 24 mA	3.0	_	_	0.55	V
		I <sub>O</sub> = 32 mA	4.5	_	_	0.55	V
V <sub>OH</sub>	HIGH-level output	$V_I = V_{IH}$ or $V_{IL}$					
	voltage	$I_{O} = -100 \mu A$	1.65 to 5.5	V <sub>CC</sub> – 0.1	_	_	V
		$I_O = -4 \text{ mA}$	1.65	1.2	_	_	V
		$I_O = -8 \text{ mA}$	2.3	1.9	_	_	V
		I <sub>O</sub> = -12 mA	2.7	2.2	_	_	V
		$I_{O} = -24 \text{ mA}$	3.0	2.3	_	_	V
		$I_{O} = -32 \text{ mA}$	4.5	3.8	_	_	V
ILI	input leakage current	$V_I = 5.5 \text{ V or GND}$	5.5	_	±0.1	±5	μΑ
l <sub>OZ</sub>	3-state output OFF-state current	$V_I = V_{IH} \text{ or } V_{IL};$ $V_O = 5.5 \text{ V or GND}$	3.6	_	±0.1	±10	μΑ
l <sub>off</sub>	power OFF leakage current	$V_I$ or $V_O = 5.5 \text{ V}$	0	_	±0.1	±10	μΑ
I <sub>CC</sub>	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0$	5.5	_	0.1	10	μΑ
$\Delta I_{CC}$	additional quiescent supply current per pin	$V_I = V_{CC} - 0.6 \text{ V};$ $I_O = 0$	2.3 to 5.5	_	5	500	μΑ

### Dual bus buffer/line driver; 3-state

### 74LVC2G126

SYMBOL PAF	DADAMETER	TEST CONDITIONS			T\(\(\mathbf{D}\)		
	PARAMETER	OTHER	V <sub>CC</sub> (V)	MIN.	TYP.	MAX.	UNIT
T <sub>amb</sub> = -40	0 to +125 °C		·	!	'	1	
V <sub>IH</sub>	HIGH-level input voltage		1.65 to 1.95	0.65 × V <sub>CC</sub>	_	_	V
			2.3 to 2.7	1.7	_	_	V
			2.7 to 3.6	2.0	_	_	V
			4.5 to 5.5	$0.7 \times V_{CC}$	_	_	V
V <sub>IL</sub>	LOW-level input voltage		1.65 to 1.95	_	_	$0.35 \times V_{CC}$	V
			2.3 to 2.7	_	_	0.7	V
			2.7 to 3.6	_	_	0.8	V
			4.5 to 5.5	_	_	$0.3 \times V_{CC}$	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$					
		I <sub>O</sub> = 100 μA	1.65 to 5.5	_	_	0.1	V
		$I_O = 4 \text{ mA}$	1.65	_	_	0.70	V
		$I_O = 8 \text{ mA}$	2.3	_	_	0.45	V
		$I_O = 12 \text{ mA}$	2.7	_	_	0.60	V
		$I_O = 24 \text{ mA}$	3.0	_	_	0.80	V
		$I_O = 32 \text{ mA}$	4.5	_	_	0.80	V
V <sub>OH</sub>	HIGH-level output	$V_I = V_{IH}$ or $V_{IL}$					
	voltage	$I_{O} = -100  \mu A$	1.65 to 5.5	V <sub>CC</sub> - 0.1	_	_	V
		$I_O = -4 \text{ mA}$	1.65	0.95	_	_	V
		$I_O = -8 \text{ mA}$	2.3	1.7	_	_	V
		$I_{O} = -12 \text{ mA}$	2.7	1.9	_	_	V
		$I_O = -24 \text{ mA}$	3.0	2.0	_	_	V
		$I_0 = -32 \text{ mA}$	4.5	3.4	_	_	V
ILI	input leakage current	$V_I = 5.5 \text{ V or GND}$	5.5	_	_	±20	μΑ
I <sub>OZ</sub>	3-state output OFF-state current	$V_I = V_{IH} \text{ or } V_{IL};$ $V_O = 5.5 \text{ V or GND}$	3.6	_	_	±20	μΑ
I <sub>off</sub>	power OFF leakage current	$V_I$ or $V_O = 5.5 \text{ V}$	0	_	_	±20	μΑ
I <sub>CC</sub>	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0$	5.5	_	_	40	μΑ
$\Delta I_{CC}$	additional quiescent supply current per pin	$V_I = V_{CC} - 0.6 \text{ V};$ $I_O = 0$	2.3 to 5.5	_	_	5000	μΑ

#### Note

<sup>1.</sup> All typical values are measured at  $V_{CC}$  = 3.3 V and  $T_{amb}$  = 25 °C.

### Dual bus buffer/line driver; 3-state

74LVC2G126

### **AC CHARACTERISTICS**

GND = 0 V.

SYMBOL	DADAMETER	TEST CON	IDITIONS		TVD	MAY	
STWIDOL	PARAMETER	WAVEFORMS	V <sub>CC</sub> (V)	MIN.	TYP.	MAX.	UNIT
T <sub>amb</sub> = -40 1	to +85 °C; note 1	•		•	•	•	
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay nA to nY	see Figs 3 and 5	1.65 to 1.95	1.0	3.9	9.8	ns
			2.3 to 2.7	0.5	2.6	4.9	ns
			2.7	1.0	2.8	4.7	ns
			3.0 to 3.6	0.5	2.4	4.3	ns
			4.5 to 5.5	0.5	1.9	3.2	ns
t <sub>PZH</sub> /t <sub>PZL</sub>	3-state output enable time	see Figs 4 and 5	1.65 to 1.95	1.0	4.1	10.0	ns
	nOE to nY		2.3 to 2.7	1.0	2.6	5.0	ns
			2.7	1.0	2.8	4.7	ns
			3.0 to 3.6	1.0	2.4	4.1	ns
			4.5 to 5.5	0.5	1.8	3.1	ns
t <sub>PHZ</sub> /t <sub>PLZ</sub>	3-state output disable time nOE to nY	see Figs 4 and 5	1.65 to 1.95	1.0	3.3	12.6	ns
			2.3 to 2.7	0.5	1.9	5.7	ns
			2.7	1.5	3.0	4.8	ns
			3.0 to 3.6	1.0	2.5	4.4	ns
			4.5 to 5.5	0.5	1.8	3.3	ns
T <sub>amb</sub> = -40 1	to +125 °C	•		•	•	•	•
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay nA to nY	see Figs 3 and 5	1.65 to 1.95	1.0	_	12.3	ns
			2.3 to 2.7	0.5	_	6.3	ns
			2.7	1.0	_	5.9	ns
			3.0 to 3.6	0.5	_	5.4	ns
			4.5 to 5.5	0.5	_	4.0	ns
t <sub>PZH</sub> /t <sub>PZL</sub>	3-state output enable time	see Figs 4 and 5	1.65 to 1.95	1.0	_	12.5	ns
	nOE to nY		2.3 to 2.7	1.0	_	6.3	ns
			2.7	1.0	_	5.9	ns
			3.0 to 3.6	1.0	_	5.1	ns
			4.5 to 5.5	0.5	_	3.9	ns
t <sub>PHZ</sub> /t <sub>PLZ</sub>	3-state output disable time	see Figs 4 and 5	1.65 to 1.95	1.0	_	15.4	ns
	nOE to nY		2.3 to 2.7	0.5	_	7.5	ns
			2.7	1.5	_	6.2	ns
			3.0 to 3.6	1.0	_	5.7	ns
			4.5 to 5.5	0.5	_	4.4	ns

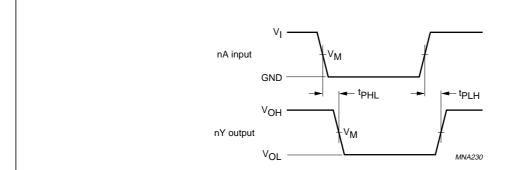
### Note

1. All typical values are measured at  $T_{amb}$  = 25 °C.

### Dual bus buffer/line driver; 3-state

### 74LVC2G126

### **AC WAVEFORMS**



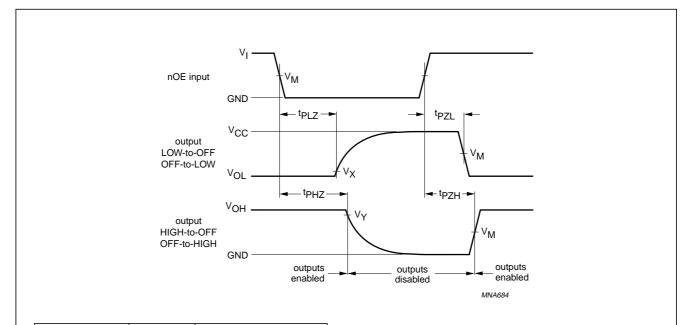
V	V	INF	UT	
V <sub>CC</sub>	V <sub>M</sub>	Vı	$t_r = t_f$	
1.65 to 1.95 V	$0.5 \times V_{CC}$	V <sub>CC</sub>	≤ 2.0 ns	
2.3 to 2.7 V	$0.5 \times V_{CC}$	V <sub>CC</sub>	≤ 2.0 ns	
2.7 V	1.5 V	2.7 V	≤ 2.5 ns	
3.0 to 3.6 V	1.5 V	2.7 V	≤ 2.5 ns	
4.5 to 5.5 V	$0.5 \times V_{CC}$	V <sub>CC</sub>	≤ 2.5 ns	

 $\rm V_{OL}$  and  $\rm V_{OH}$  are typical output voltage drop that occur with the output load.

Fig.3 The input (nA) to output (nY) propagation delays and the output transition times.

### Dual bus buffer/line driver; 3-state

### 74LVC2G126



V	V	INF	TU
V <sub>CC</sub>	V <sub>M</sub>	Vı	$t_r = t_f$
1.65 to 1.95 V	$0.5 \times V_{CC}$	V <sub>CC</sub>	≤ 2.0 ns
2.3 to 2.7 V	$0.5 \times V_{CC}$	V <sub>CC</sub>	≤ 2.0 ns
2.7 V	1.5 V	2.7 V	≤ 2.5 ns
3.0 to 3.6 V	1.5 V	2.7 V	≤ 2.5 ns
4.5 to 5.5 V	$0.5 \times V_{CC}$	V <sub>CC</sub>	≤ 2.5 ns

$$\begin{split} V_X &= V_{OL} + 0.3 \text{ V at } V_{CC} \geq 2.7 \text{ V}; \\ V_X &= V_{OL} + 0.15 \text{ V at } V_{CC} < 2.7 \text{ V}; \end{split}$$

 $V_X = V_{OL} + 0.15 \text{ V at } V_{CC} < 2.7 \text{ V}$  $V_Y = V_{OH} - 0.3 \text{ V at } V_{CC} \ge 2.7 \text{ V};$ 

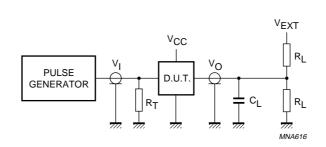
 $V_{Y}$  =  $V_{OH} - 0.15 \; V$  at  $V_{CC} < 2.7 \; V.$ 

 $\ensuremath{V_{\text{OL}}}$  and  $\ensuremath{V_{\text{OH}}}$  are typical output voltage drop that occur with the output load.

Fig.4 3-state enable and disable times.

### Dual bus buffer/line driver; 3-state

### 74LVC2G126



V <sub>CC</sub>	Vı	C.	R <sub>L</sub>	V <sub>EXT</sub>		
▼CC	"	CL	I IL	t <sub>PLH</sub> /t <sub>PHL</sub>	t <sub>PZH</sub> /t <sub>PHZ</sub>	t <sub>PZL</sub> /t <sub>PLZ</sub>
1.65 to 1.95 V	V <sub>CC</sub>	30 pF	1 kΩ	open	GND	$2 \times V_{CC}$
2.3 to 2.7 V	V <sub>CC</sub>	30 pF	500 Ω	open	GND	$2 \times V_{CC}$
2.7 V	2.7 V	50 pF	500 Ω	open	GND	6 V
3.0 to 3.6 V	2.7 V	50 pF	500 Ω	open	GND	6 V
4.5 to 5.5 V	V <sub>CC</sub>	50 pF	500 Ω	open	GND	$2 \times V_{CC}$

Definitions for test circuit:

 $R_L$  = Load resistor.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

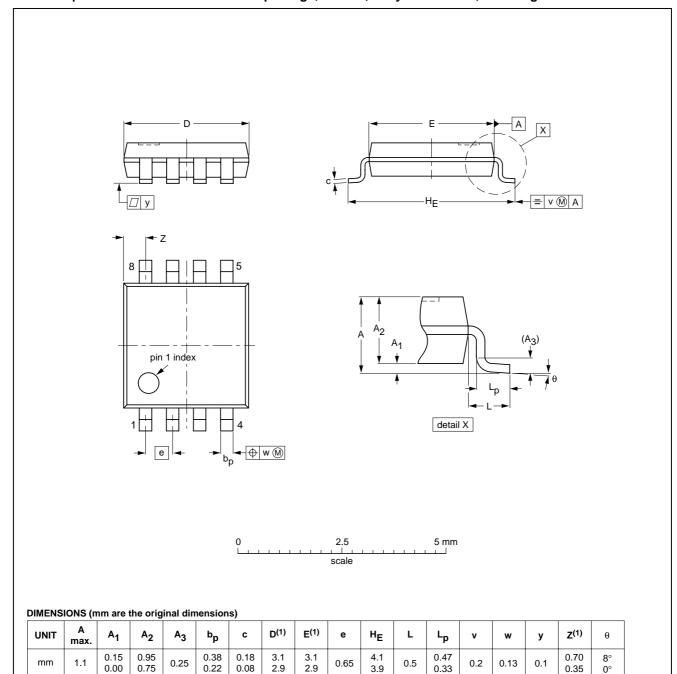
Fig.5 Load circuitry for switching times.

### Dual bus buffer/line driver; 3-state

74LVC2G126

#### **PACKAGE OUTLINES**

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm SOT505-2



### Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

0.08

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT505-2						02-01-16

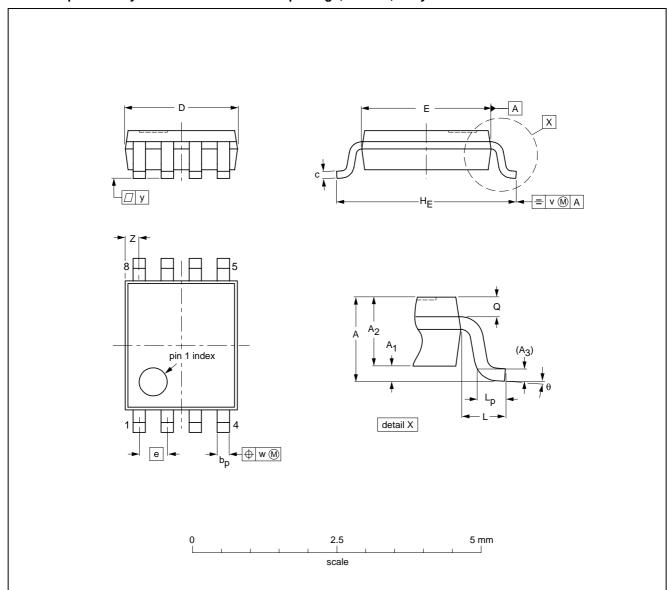
2003 Sep 01 11

### Dual bus buffer/line driver; 3-state

### 74LVC2G126

### VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1



#### **DIMENSIONS** (mm are the original dimensions)

UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	А3	bp	С	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1	0.15 0.00	0.85 0.60	0.12	0.27 0.17	0.23 0.08	2.1 1.9	2.4 2.2	0.5	3.2 3.0	0.4	0.40 0.15	0.21 0.19	0.2	0.13	0.1	0.4 0.1	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT765-1		MO-187				02-06-07	

### Dual bus buffer/line driver; 3-state

74LVC2G126

#### **DATA SHEET STATUS**

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS(2)(3)	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

#### **Notes**

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

#### **DEFINITIONS**

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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